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# P-Channel 40 V (D-S) MOSFET

### **DESCRIPTION**

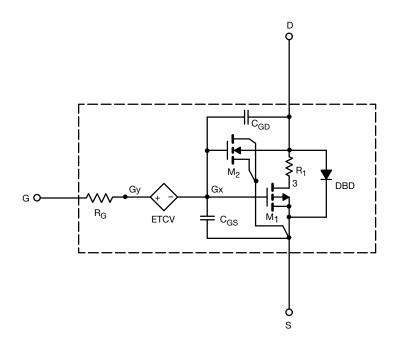
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -  $55\,^{\circ}$ C to +  $125\,^{\circ}$ C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



#### Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model SUD50P04-08**

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	1.9	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 22 A	0.0068	0.0067	Ω
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 19 A	0.010	0.0097	
Forward Transconductance <sup>a</sup>	9fs	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 22 A	56	45	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = - 10 A	- 0.77	- 0.80	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = - 20 V, V <sub>GS</sub> = 0 V, f = 1 MHz	5360	5380	pF
Output Capacitance	C <sub>oss</sub>		568	570	
Reverse Transfer Capacitance	C <sub>rss</sub>		498	500	
Total Gate Charge	Qg	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	104	106	
			55	60	0
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -20 \text{ A}$	22	22	nC
Gate-Drain Charge	Q <sub>qd</sub>	1	27	27	

### Notes

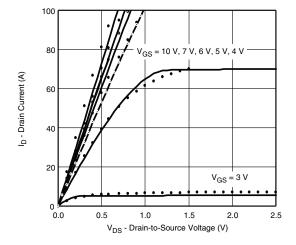
- a. Pulse test; pulse width  $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

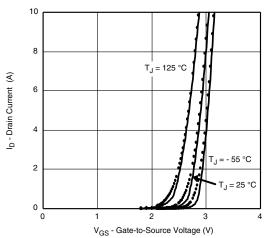


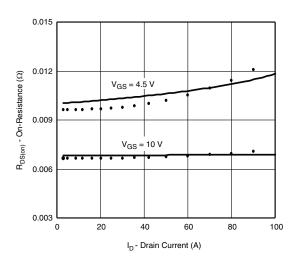
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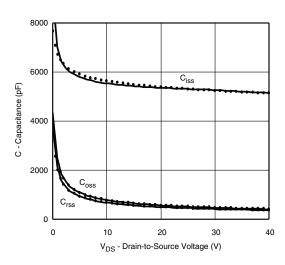
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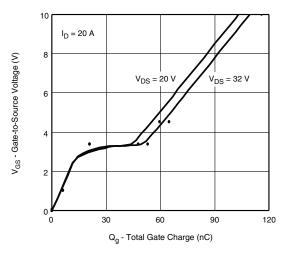
### COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25$ °C, unless otherwise noted

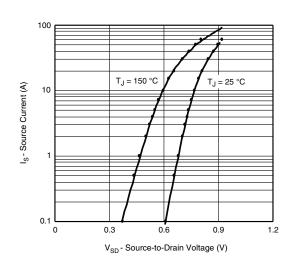










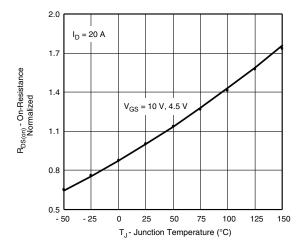


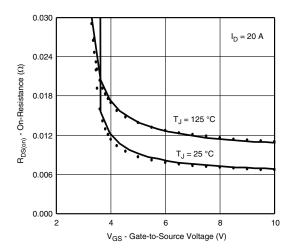
**Note**Dots and squares represent measured data.

# **SPICE Device Model SUD50P04-08**

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## COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~{\rm ^{\circ}C}$ , unless otherwise noted





### Note

Dots and squares represent measured data.



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